HEF4938B

Dual precision monostable multivibrator Rev. 6 — 15 November 2011

Product data sheet

General description 1.

The HEF4938B is a dual retriggerable-resettable monostable multivibrator. Each multivibrator has an active LOW trigger/retrigger input (nA), an active HIGH trigger/retrigger input (nB), an overriding active LOW direct reset input (nCD), an output (nQ) and its complement (nQ), and two pins (CEXT, always connected to ground, and nREXT/CEXT) for connecting the external timing components CEXT and REXT. The typical pulse width variation over the specified temperature range is ± 0.2 %.

The multivibrator may be triggered by either the positive or the negative edges of the input pulse and will produce an accurate output pulse with a pulse width range of 10 μs to infinity. The duration and accuracy of the output pulse are determined by the external timing components C_{EXT} and R_{EXT} . The output pulse width (t_W) is equal to $R_{EXT} \times C_{EXT}$. The linear design techniques in LOCMOS (Local Oxide CMOS) guarantee precise control of the output pulse width. A LOW level at nCD terminates the output pulse immediately. The trigger inputs' Schmitt trigger action makes the circuit highly tolerant of slower rise and fall times.

It operates over a recommended V_{DD} power supply range of 3 V to 15 V referenced to V_{SS} (usually ground). Unused inputs must be connected to V_{DD}, V_{SS}, or another input.

2. Features and benefits

- Separate reset inputs
- Triggering from leading or trailing edge
- Tolerant of slow trigger rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Specified from -40 °C to +85 °C
- Complies with JEDEC standard JESD 13-B

Ordering information 3.

Table 1. **Ordering information**

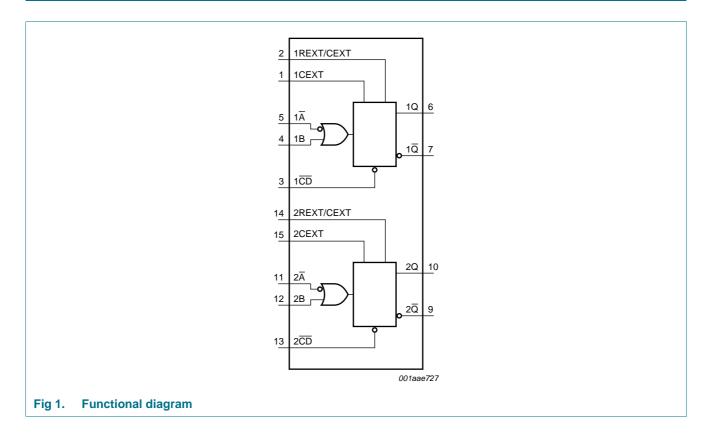
All types operate from -40 °C to +85 °C.

Type number	Package		
	Version		
HEF4938BP	DIP16	plastic dual in-line package; 16 leads (300 mil)	SOT38-4
HEF4938BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1

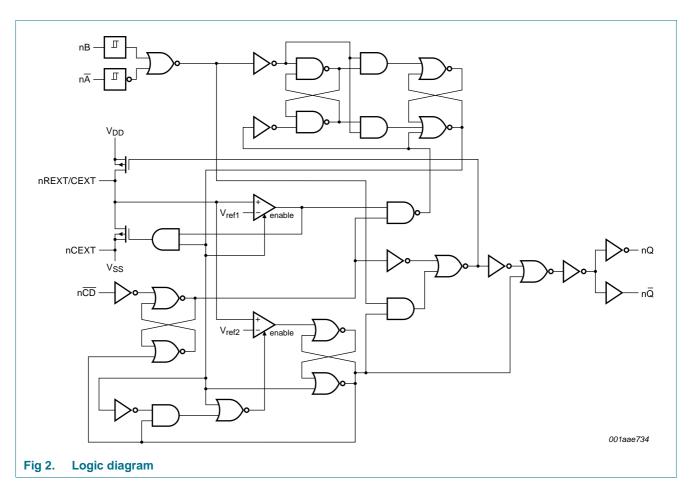


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4. Functional diagram

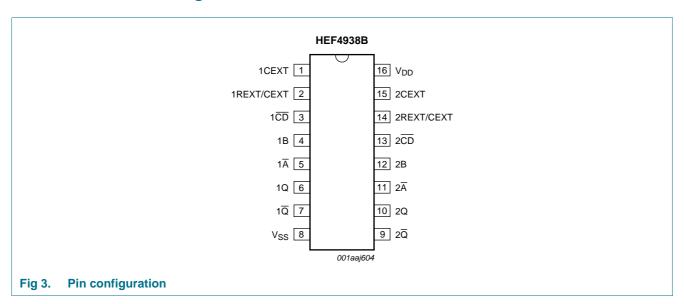


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5. Pinning information

5.1 Pinning



HEF4938B

Dual precision monostable multivibrator

5.2 Pin description

Table 2. Pin description

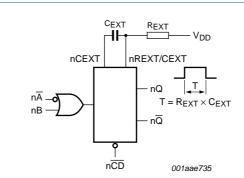
Symbol	Pin	Description
1CEXT, 2CEXT	1, 15	external capacitor connection (always connected to ground)
1REXT/CEXT, 2REXT/CEXT	2, 14	external capacitor/resistor connection
1 CD , 2 CD	3, 13	direct reset input (active LOW)
1B, 2B	4, 12	input (LOW-to-HIGH triggered)
1 A , 2 A	5, 11	input (HIGH-to-LOW triggered)
1Q, 2Q	6, 10	output
1 Q , 2 Q	7, 9	complementary output (active LOW)
V _{SS}	8	ground supply voltage
V_{DD}	16	supply voltage

6. Functional description

Table 3. Function table[1]

Inputs			Outputs		
nĀ	nB	nCD	nQ	nQ	
\	L	Н	Л	T	
Н	\uparrow	Н	Л	T	
Χ	X	L	L	Н	

- [1] H = HIGH voltage level; L = LOW voltage level; X = don't care; ↑ = positive-going transition; ↓ = negative-going transition;
 - \square = one HIGH level output pulse, with the pulse width determined by C_{EXT} and R_{EXT} ;
 - \square = one LOW level output pulse, with the pulse width determined by C_{EXT} and R_{EXT} .

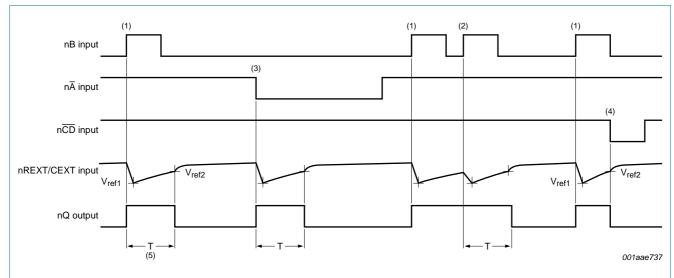


The external timing resistor R_{EXT} minimum value is 5 k Ω . Its maximum permissible resistance, which holds the specified accuracy of t_W (nQ, n \overline{Q} output), depends on the leakage current of the capacitor C_{EXT} and the leakage of the HEF4938B.

The external timing capacitor C_{EXT} minimum value is 2000 pF with no upper limit.

Fig 4. Connection of the external timing components R_{EXT} and C_{EXT}

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- (1) Positive edge triggering.
- (2) Positive edge retriggering (pulse lengthening).
- (3) Negative edge triggering.
- (4) Reset (pulse shortening).
- (5) $T = R_{EXT} \times C_{EXT}$.

Fig 5. Timing diagram

7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to V_{SS} = 0 V (ground)

Symbol	Parameter	Conditions	Min	Max	Unit
V_{DD}	supply voltage		-0.5	+18	V
I _{IK}	input clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$	-	±10	mA
VI	input voltage		-0.5	$V_{DD} + 0.5$	V
lok	output clamping current	$V_I < -0.5 \text{ V or } V_I > V_{DD} + 0.5 \text{ V}$		±10	mA
I _{I/O}	input/output current		-	±10	mA
I_{DD}	supply current			50	mA
T _{stg}	storage temperature		-65	+150	°C
T _{amb}	ambient temperature		-40	+125	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +85 ^{\circ}\text{C}$			
		DIP16 package	<u>[1]</u> _	750	mW
		SO16 package	[2] _	500	mW
Р	power dissipation	per output	-	100	mW

^[1] For DIP16 package: P_{tot} derates linearly with 12 mW/K above 70 $^{\circ}\text{C}.$

^[2] For SO16 package: P_{tot} derates linearly with 8 mW/K above 70 $^{\circ}\text{C}.$

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8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V_{DD}	supply voltage		3	-	15	V
VI	input voltage		0	-	V_{DD}	V
T _{amb}	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{DD} = 5 V$	-	-	3.75	μs/V
		V _{DD} = 10 V	-	-	0.5	μs/V
		V _{DD} = 15 V	-	-	0.08	μs/V

9. Static characteristics

Table 6. Static characteristics

 $V_{SS} = 0$ V; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	–40 °C	T _{amb} =	25 °C	T _{amb} =	85 °C	Unit
				Min	Max	Min	Max	Min	Max	
V_{IH}	HIGH-level input voltage	$ I_O < 1 \mu A$	5 V	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	V
V_{IL}	LOW-level input voltage	$ I_{O} < 1 \mu A$	5 V	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	V
V _{OH} HIGH-level output voltage	$ I_O < 1 \mu A$	5 V	4.95	-	4.95	-	4.95	-	V	
			10 V	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	V
V_{OL}	LOW-level output voltage	$ I_O < 1 \mu A$	5 V	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	V
I_{OH}	HIGH-level output current	$V_0 = 2.5 \text{ V}$	5 V	-	-1.7	-	-1.4	-	-1.1	mΑ
		$V_0 = 4.6 \text{ V}$	5 V	-	-0.64	-	-0.5	-	-0.36	mΑ
		$V_0 = 9.5 V$	10 V	-	-1.6	-	-1.3	-	-0.9	mΑ
		$V_0 = 13.5 \text{ V}$	15 V	-	-4.2	-	-3.4	-	-2.4	mΑ
I_{OL}	LOW-level output current	$V_0 = 0.4 \text{ V}$	5 V	0.64	-	0.5	-	0.36	-	mΑ
		$V_0 = 0.5 V$	10 V	1.6	-	1.3	-	0.9	-	mΑ
		$V_0 = 1.5 \text{ V}$	15 V	4.2	-	3.4	-	2.4	-	mΑ
II	input leakage current	pins 2 and 14	15 V	-	±0.1	-	±0.1	-	±1.0	μΑ
I_{DD}	supply current	active state	5 V [1]	-	-	(Typica	ıl = 55)	-	-	μΑ
			10 V	-	-	(Typical	= 150)	-	-	μΑ
			15 V	-	-	(Typical	= 220)	-	-	μΑ

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Table 6. Static characteristics ...continued

 $V_{SS} = 0 \ V$; $V_I = V_{SS}$ or V_{DD} unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	T _{amb} =	T _{amb} = -40 °C		T _{amb} = 25 °C		T _{amb} = 85 °C	
				Min	Max	Min	Max	Min	Max	
I_{DD}	supply current	$I_O = 0 A$	5 V	-	5	-	5	-	150	μΑ
			10 V	-	10	-	10	-	300	μΑ
			15 V	-	20	-	20	-	600	μΑ
Cı	input capacitance		-	-	-	-	7.5	-	-	pF

^[1] Only one monostable is switching: current present during output pulse (output Q is HIGH).

10. Dynamic characteristics

Table 7. Dynamic characteristics

 $V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \text{ °C}$; for test circuit see <u>Figure 11</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula[1]	Min	Тур	Max	Unit
t _{PHL}	HIGH to LOW	$n\overline{A}$, nB to $n\overline{Q}$;	5 V	193 ns + (0.55 ns/pF)C _L	-	220	440	ns
	propagation delay	see <u>Figure 6</u>	10 V	74 ns + (0.23 ns/pF)C _L	-	85	190	ns
			15 V	52 ns + (0.16 ns/pF)C _L	-	60	120	ns
		nCD to nQ; see Figure 6	5 V	98 ns + (0.55 ns/pF)C _L	-	125	250	ns
			10 V	44 ns + (0.23 ns/pF)C _L	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _{PLH}	LOW to HIGH	$n\overline{A}$, nB to nQ;	5 V	173 ns + (0.55 ns/pF)C _L	-	200	460	ns
	propagation delay	see Figure 6	10 V	79 ns + (0.23 ns/pF)C _L	-	90	180	ns
			15 V	52 ns + (0.16 ns/pF)C _L	-	60	120	ns
		nCD to nQ; see Figure 6	5 V	98 ns + (0.55 ns/pF)C _L	-	125	250	ns
			10 V	44 ns + (0.23 ns/pF)C _L	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF)C _L	-	40	80	ns
t _{rec}	recovery time	nCD to nA, nB; see <u>Figure 7</u>	5 V		-	20	40	ns
			10 V		-	10	20	ns
			15 V		-	5	10	ns
t _{rtrig}	retrigger time	nQ , $n\overline{Q}$ to $n\overline{A}$, nB ;	5 V		0	-	-	ns
		see Figure 7	10 V		0	-	-	ns
			15 V		0	-	-	ns
t _W	pulse width	A input LOW;	5 V		90	45	-	ns
		minimum width;	10 V		30	15	-	ns
		see Figure 7	15 V		24	12	-	ns
		nB input HIGH;	5 V		50	25	-	ns
		minimum width;	10 V		24	12	-	ns
		see <u>Figure 7</u>	15 V		20	10	-	ns
		nQ or $n\overline{Q}$ output;	5 V		9.3	10.0	10.6	ms
		$R_{EXT} = 100 \text{ k}\Omega;$ $C_{EXT} = 0.1 \mu\text{F};$ see Figure 7	10 V		9.2	9.9	10.5	ms
			15 V		9.1	9.8	10.4	ms

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 Table 7.
 Dynamic characteristics ...continued

 $V_{SS} = 0 \text{ V}$; $T_{amb} = 25 \text{ °C}$; for test circuit see <u>Figure 11</u>; unless otherwise specified.

Symbol	Parameter	Conditions	V_{DD}	Extrapolation formula[1]	Min	Тур	Max	Unit
Δt_{W}	pulse width	nQ or $n\overline{Q}$ output	5 V		-	±0.2	-	%
	variation	variation over temperature (T _{amb})	10 V		-	±0.2	-	%
		range; see Figure 8	15 V		-	±0.2	-	%
		nQ or $n\overline{Q}$ output variation over V_{DD} voltage range 5 V to 15 V; see <u>Figure 9</u>			-	±1.5	-	%
		nQ or nQ output variation between same	5 V		-	±1	-	%
			10 V		-	±1	-	%
		package devices; R_{EXT} = 100 kΩ; C_{EXT} = 2 nF to 10 μF	15 V		-	±1	-	%
C _I	input capacitance	nREXT/CEXT			-	15	-	pF

^[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C_L in pF).

11. Waveforms

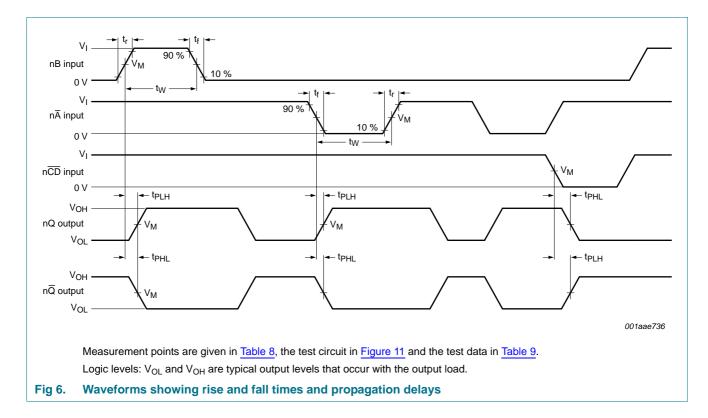


Table 8. Measurement points

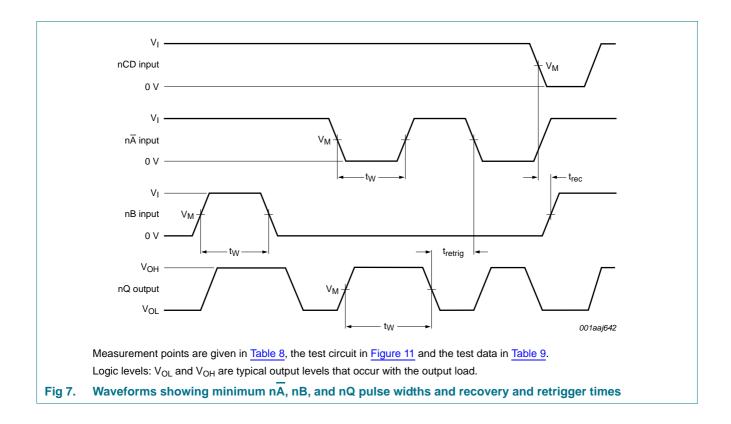
Supply voltage	Input	Output
V _{DD}	V _M	V _M
5 V to 15 V	0.5V _{DD}	0.5V _{DD}

HEF4938E

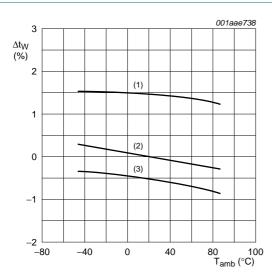
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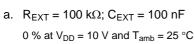
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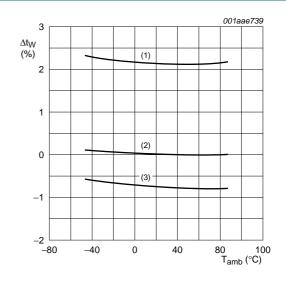


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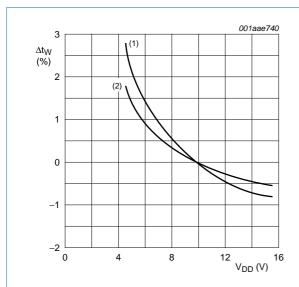


- (1) $V_{DD} = 5 \text{ V}.$
- (2) $V_{DD} = 10 \text{ V}.$
- (3) $V_{DD} = 15 \text{ V}.$



b. $R_{EXT} = 100 \text{ k}\Omega$; $C_{EXT} = 2 \text{ nF}$

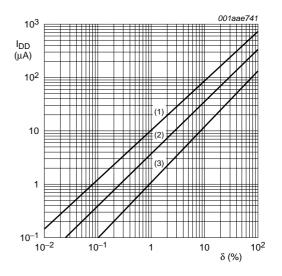




 T_{amb} = 25 °C; 0 % at V_{DD} = 10 V; R_{EXT} = 100 $k\Omega$

- (1) $C_{EXT} = 2 \text{ nF}.$
- (2) $C_{EXT} = 100 \text{ nF}.$

Fig 9. Typical normalized change in output pulse width as a function of the supply voltage

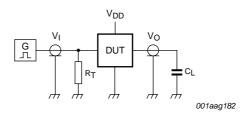


 R_{EXT} = 100 k Ω ; C_{EXT} = 100 nF; C_L = 50 pF; one monostable multivibrator switching only

- (1) $V_{DD} = 15 \text{ V}.$
- (2) $V_{DD} = 10 \text{ V}.$
- (3) $V_{DD} = 5 \text{ V}.$

Fig 10. Total supply current as a function of the output duty factor

Dual precision monostable multivibrator



Test data is given in Table 9.

Definitions for test circuit:

DUT = Device Under Test.

 C_L = load capacitance including jig and probe capacitance.

 R_T = termination resistance should be equal to the output impedance Z_o of the pulse generator.

Fig 11. Test circuit

Table 9. Test data

Supply voltage	Input	Load	
V_{DD}	VI	t _r , t _f	CL
5 V to 15 V	V _{SS} or V _{DD}	≤ 20 ns	50 pF

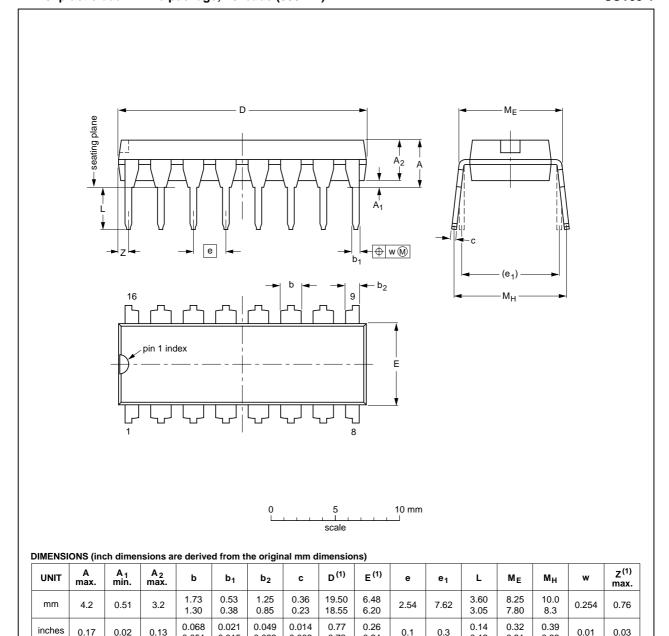
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Dual precision monostable multivibrator

12. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4



Note

0.17

1. Plastic or metal protrusions of 0.25 mm (0.01 inch) maximum per side are not included.

0.015

0.033

0.009

0.051

OUTLINE	REFER	ENCES	EUROPEAN	ISSUE DATE	
VERSION	IEC	JEDEC	JEITA	PROJECTION	ISSUE DATE
SOT38-4					95-01-14 03-02-13

0.1

Fig 12. Package outline SOT38-4 (DIP16)

0.02

0.13

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0.01

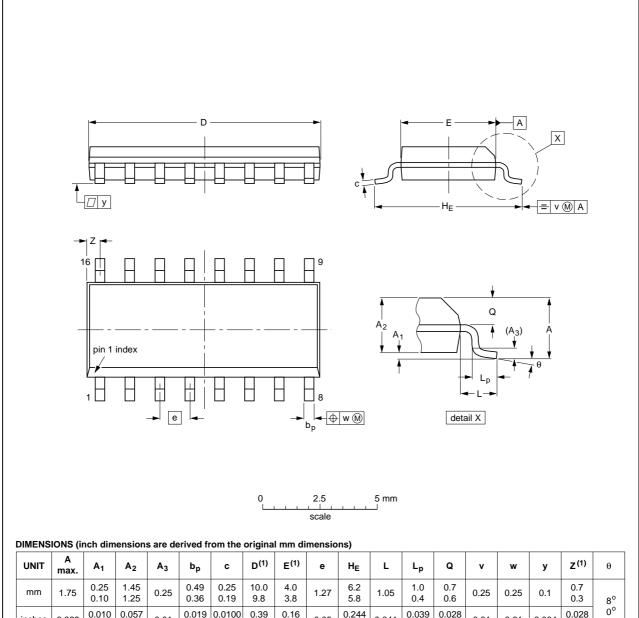
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SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



UNIT	A max.	A ₁	A ₂	A ₃	bp	С	D ⁽¹⁾	E ⁽¹⁾	е	HE	L	Lp	Q	٧	w	у	Z ⁽¹⁾	θ
mm	1.75	0.25 0.10	1.45 1.25	0.25	0.49 0.36	0.25 0.19	10.0 9.8	4.0 3.8	1.27	6.2 5.8	1.05	1.0 0.4	0.7 0.6	0.25	0.25	0.1	0.7 0.3	8°
inches	0.069	0.010 0.004	0.057 0.049	0.01	1	0.0100 0.0075	0.39 0.38	0.16 0.15	0.05	0.244 0.228	0.041	0.039 0.016		0.01	0.01	0.004	0.028 0.012	0°

Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT109-1	076E07	MS-012				99-12-27 03-02-19	

Fig 13. Package outline SOT109-1 (SO16)

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13. Revision history

Table 10. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4938B v.6	20111115	Product data sheet	-	HEF4938B v.5
Modifications:	 Section App 	olications removed		
	• Table 6: I _{OF}	_t minimum values changed t	o maximum	
	• <u>Figure 11</u> : a	added "DUT = Device Under	Test"	
HEF4938B v.5	20100106	Product data sheet	-	HEF4938B v.4
HEF4938B v.4	20090309	Product data sheet	-	HEF4938B_CNV v.3
HEF4938B_CNV v.3	19950101	Product specification	-	HEF4938B_CNV v.2
HEF4938B_CNV v.2	19950101	Product specification	-	-

Dual precision monostable multivibrator

14. Legal information

14.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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